

LPS1100



POWER THICK FILM RESISTOR



High-Power Thick Film Resistor Heatsink Mounting



KEY BENEFITS

- High power up to 1100 W at 25 °C on heatsink
- Small size and low profile, 57 mm x 60 mm
- Non inductive: < 0.1 µH
- High dielectric strength up to 12 kV_{RMS}
- Low weight: 79 g
- High temperature up to 200 °C
- Compliant to RoHS Directive 2011/65/EU

APPLICATIONS

- Industrial (windmills)
- Transportation (trains)
- Medical (x-ray tables)
- HEV/EV (battery management)

RESOURCES

- Datasheet: LPS1100 http://www.vishay.com/doc?50059
- Application Note http://www.vishay.com/doc?52025
- For technical questions contact <u>sfer@vishay.com</u>

One of the World's Largest Manufacturers of Discrete Semiconductors and Passive Components



PRODUCT SHEET

VMN-PT0311-1202



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Notes

Tolerances unless stated: ± 0.2 mm

Power dissipation is 1100 W by using a water cooled heatsink at T_{water} = 15 °C of R_{th} = 0.059 °C/W (25 °C to the nearest point of the resistor onto heatsink) and R_{th} contact estimated at 0.07 °C/W.

MECHANICAL SPECIFICATIONS

Mechanical Protection	Insulated case and resin for potting UL 94 V-0			
Resistive Element	Thick film			
End Connections	Screws M4			
Tightening Torque Connections 2 Nm				
Tightening Torque Heatsin	k 2 Nm			
Maximum Torque	2.5 Nm			
Weight	79 g ± 10 %			

ENVIRONMENTAL SPECIFICATIONS

Temperature Range	- 55 °C to + 200 °C
Climatic Category	55/200/56

$\begin{tabular}{|c|c|c|c|c|} \hline \textbf{ELECTRICAL SPECIFICATIONS} \\ \hline \textbf{Resistance Range} & 1 Ω to 1.3 kΩ \\ \hline \textbf{Tolerances} & $\pm 1 $\%$ to $\pm 10 $\%$ \\ \hline \textbf{Power Rating and} & 1100 W at $\pm 25 $^\circ$C$ \\ \hline \textbf{On heatsink} & $On heatsink$ \\ \hline \textbf{On heatsink} & On

Inermal Resistance	R _{th(j-c)} : 0.039 °C/W	
Temperature Coefficient (- 55 °C to + 200 °C), IEC 60115-1	ent ± 150 ppm/°C	
Dielectric Strength IEC 60115-1, 1 min, 10 mA max.	7 kV _{RMS} or 12 kV _{RMS}	
Insulation	$\geq 10^4 \ \text{M}\Omega$	
Inductance	≤ 0.1 μH	

	PERFORMANCE		
	TESTS	CONDITIONS	REQUIREMENTS
	Momentary Overload	$\label{eq:lecond} \begin{array}{l} \text{IEC 60115-1: } 2 \text{ x } \text{Pr/10 s for heatsink with} \\ \text{R}_{\text{th}(h\text{-}a)} \geq 0.26 \ ^{\circ}\text{C/W} \ (\text{maximum power: 700 W}) \\ \text{1.6 x } \text{Pr/1 s for heatsink with } 0.26 \ ^{\circ}\text{C/W} > \text{R}_{\text{th}(h\text{-}a)} \geq 0.059 \ ^{\circ}\text{C/W} \\ (\text{maximum power: 1800 W}) \end{array}$	± (0.25 % + 0.05 Ω)
	Rapid Temperature Change	AEC-Q200 conditions: IEC 60115-1/IEC 60068-2-14, Test Na 50 cycles (- 55 °C to + 200 °C)	\pm (0.5 % + 0.05 $\Omega) for all the ohmic values$
		1000 cycles (- 55 °C to + 200 °C)	\pm (5 % + 0.05 Ω) for R < 38 U ± (0.5 % + 0.05 Ω) for R ≥ 38 U
	Load Life	AEC-Q200 conditions: IEC 60115-1 1000 h (90/30) Pr	\pm (5 % + 0.05 Ω) for R < 38 U ± (0.5 % + 0.05 Ω) for R ≥ 38 U
N	Humidity (Steady State)	AEC-Q200 conditions: IEC 60115-1, 1000 h RH 85 %/85 °C	± (0.5 % + 0.05 Ω)
-Feb-1	Mechanical Shock	AEC-Q200 conditions: MIL-STD-202 method 213 condition D (100 g's/6 ms 3.75 m/s)	± (1 % + 0.05 Ω)
sion 13	Vibration	AEC-Q200 conditions: MIL-STD-202 method 204 condition D (5 g, 20 min 10/2000 Hz)	± (1 % + 0.05 Ω)
Revi	Climatic Sequence	AEC-Q200 conditions: IEC 60115-1 (55/200/56)	± (1 % + 0.05 Ω)

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